

A novel technique for probing phase transitions in ferroelectric functional materials: Condensed matter spectroscopy

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As relaxor ferroelectric functional materials, their crystal structures depend on temperature, component, electric field, pressure, and so on, which are important for the applications of sensors, transducers, and actuators. For the case of PbTiO_3 -based ferroelectrics $\text{Pb}(\text{Zn}_{1/3}\text{Nb}_{2/3})\text{O}_3$ - PbTiO_3 , $\text{Pb}(\text{Mg}_{1/3}\text{Nb}_{2/3})\text{O}_3$ - PbTiO_3 , $\text{Pb}(\text{In}_{1/2}\text{Nb}_{1/2})\text{O}_3$ - $\text{Pb}(\text{Mg}_{1/3}\text{Nb}_{2/3})\text{O}_3$ - PbTiO_3 and some other crystals, they have been extensively investigated due to the excellent electromechanical and piezoelectric properties. Generally, ferroelectric crystal structure and corresponding phase diagram are detected by temperature-dependent high resolution X-ray diffraction, low frequency dielectric permittivity, and domain structures. In this review, we focus on the novel condensed matter spectroscopy (i.e., spectroscopic ellipsometry, transmittance, photoluminescence spectra as well as Raman spectra), which is nondestructive, noncontact, and sensitive optical techniques for probing symmetries, phase transitions and phase diagrams of ferroelectric crystals. Besides, it can supply some other physical and chemical information for ferroelectric and semiconductor functional materials such as optical band gap, electronic transitions, dielectric functions, optical conductivity, absorption, phonon modes, lattice dynamics as functions of temperature and PT composition.

ferroelectrics, phase diagram, Raman scattering, ellipsometric spectroscopy, transmittance, photoluminescence

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1 Introduction

Recently, perovskite ferroelectric functional materials have attracted considerable attention and intensive research from the viewpoint of excellent ferroelectric and piezoelectric properties for the understanding of fundamental physics and applications in multifunction devices [1–7]. In particular, PbTiO_3 (PT)-based perovskite ferroelectric materials, such as $\text{Pb}(\text{Zn}_{1/3}\text{Nb}_{2/3})\text{O}_3$ - $x\text{PbTiO}_3$ (PZN- x PT), $\text{Pb}(\text{Mg}_{1/3}\text{Nb}_{2/3})\text{O}_3$ - $x\text{PbTiO}_3$ (PMN- x PT), and $(1-x-y)\text{Pb}(\text{In}_{1/2}\text{Nb}_{1/2})\text{O}_3$ - $y\text{Pb}(\text{Mg}_{1/3}\text{Nb}_{2/3})\text{O}_3$ - $x\text{PbTiO}_3$ (PIN- y PMN- x PT), have been widely investigated due to their excellent piezoelectric coefficient, strain levels reaching induced by electric field, and

a high electromechanical coupling coefficient especially for the PT composition near a morphotropic phase boundary (MPB), which are essential for the technological applications of ultrasonic transducers, solid actuators, and sonar [8–15]. The MPB is a phase boundary, which separates different crystal structures in a phase diagram. For PZN- x PT and PMN- x PT functional materials at room temperature, it corresponds to $x \sim 8\%–10\%$ and $x \sim 26\%–39\%$, respectively [16,17]. Accurately, the MPB separates the ferroelectric rhombohedral phase and ferroelectric tetragonal one in the phase diagram of PZN- x PT (PMN- x PT) [18,19]. A schematic phase diagram and related polarization-rotation path of the PT-based relaxor ferroelectrics (PZN- x PT, PMN- x PT, $(1-x-y)$ PIN- y PMN- x PT, etc.) are shown in Figure 1 [3]. Generally, the crystal structure is cubic (C) symmetry above

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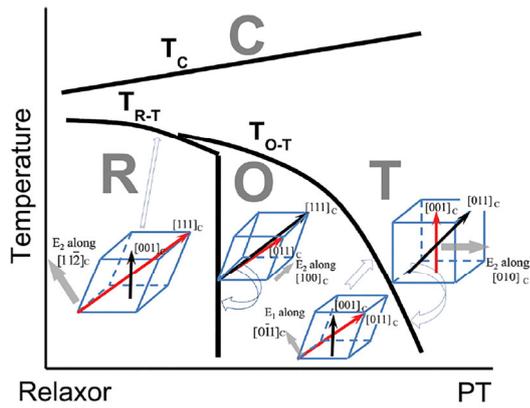


Figure 1 (Color online) A schematic phase diagram and polarization rotations for PT-based relaxor ferroelectric crystals [3].

the Curie temperature (T_C). On the other hand, there are different symmetries including rhombohedral (R), orthorhombic (O), and tetragonal (T) phases in different temperature regions and PT compositions below T_C . It should be noted that the O phase is used instead of the monoclinic (M) phase since the M phase is a slightly distorted O phase. According to the phase diagram, PT-based ferroelectrics with the x composition below MPB undergo R-T-C phase transitions. While above MPB, they have a T→C phase transition upon heating [1,15–18]. Moreover, it is reported that PZN- x PT crystals with the PT composition near MPB exhibit excellent optical properties. For example, PZN-8%PT has a relative large electro-optic (~ 450 pm/V poled along [001] direction) and photoelastic coefficient ($\sim 19 \times 10^{-12}$ m²/N), which are expected to be applied in various linear and nonlinear optical devices [20,21].

Usually, crystal structures and phase diagrams can be identified by traditional techniques: X-ray diffraction based on the various trends of lattice constants (a , b , and c) and angles (α , β , and γ) as a function of temperature [18,22,23]; For ferroelectrics, temperature dependence of dielectric permittivity in the low frequency region below 10^6 Hz is an effective method to detect phase transitions especially Curie temperature, which is the phase transition between ferroelectric and paraelectric phases [24–29]; Polarizing light microscopy also can detect phase transitions according to various domain structures at different temperatures [30–32]. In addition, there are some other techniques such as neutron diffraction, transmission electron microscope (TEM), birefringence imaging measurements for probing phase transitions and phase diagrams [16,17,33]. However, there are some disadvantages of traditional techniques as following: 1) X-ray diffraction cannot supply more physical properties (optical, electric, and thermal properties) besides that of crystal structures; 2) low frequency electric measurements are contact type with electrodes, which are often complicated and hindered by parasitic charges forming at interface and electrodes; 3) sample preparation of TEM is very ex-

pensive. Compared to the traditional techniques (X-ray diffraction, low frequency electric measurements, TEM, etc.), the novel condensed matter spectroscopy is nondestructive, noncontact, and sensitive for probing phase diagrams, and can supply more information of physical and chemical properties such as temperature response of optical band gap, electronic transitions, optical constants, absorption, phonon modes, lattice dynamics [34–46]. As a condensed matter spectroscopy, Raman scattering is an effective technique to study ferroelectric phase transitions base on the various trends of peak position, integrated intensity, and bandwidth of first-order Raman modes on heating or cooling [34–40]. Besides, some other optical methods such as spectroscopic ellipsometry (SE), transmittance, photoluminescence (PL), and infrared spectra, are used to probe ferroelectric phase transitions and phase diagrams [41–46].

The review is organized as follows: Section 2 presents the traditional techniques (X-ray diffraction, low frequency dielectric permittivity, polarizing light microscopy, etc.) to obtain ferroelectric crystal structures and phase diagrams below and above room temperature. For the case of PbTiO₃-base functional ferroelectrics, temperature dependent condensed matter spectroscopy, which is related to phase transitions and diagrams as well as optical properties, are described in detail in Section 3. Finally, conclusion and prospect are drawn in Section 4.

2 Traditional techniques

2.1 Temperature-dependent X-ray diffraction

X-ray diffraction (XRD) is a rapid and nondestructive tool for structure characterization of functional materials [47–49]. For ferroelectrics, it can be used to determine lattice parameters, crystal symmetries, expansion tensors, phase transitions, etc. [22,23,38]. The 25%PIN-42%PMN-33%PT crystals are grown from the melt by a modified Bridgman method [4,50] and its pseudo-cubic (002) and (220) diffraction peaks at the zero-field-cooling (ZFC) and zero-field-heating (ZFH) conditions have been investigated in detail (not shown) [4]. At high temperature above 190°C, the C phase is stable since a single sharp peak is observed. A transition from C phase to T phase appears on cooling to 180°C due to an additional peak at lower scattering angle. On further cooling to 140°C, a coexistence of C and T is observed due to the tetragonal (002)-(200) doublet and residual cubic (002) singlet. Finally, the broad rhombohedral (002) singlet appears at the temperature below 110°C. In addition, it has the same phase transitions (R-T-C) upon heating [4]. Based on the XRD patterns of 25%PIN-42%PMN-33%PT crystals, the lattice parameters and angles have various trends on cooling/heating without applying electric field as shown in Figure 2. It indicates that 25%PIN-42%PMN-33%PT undergoes R-T-C transitions.

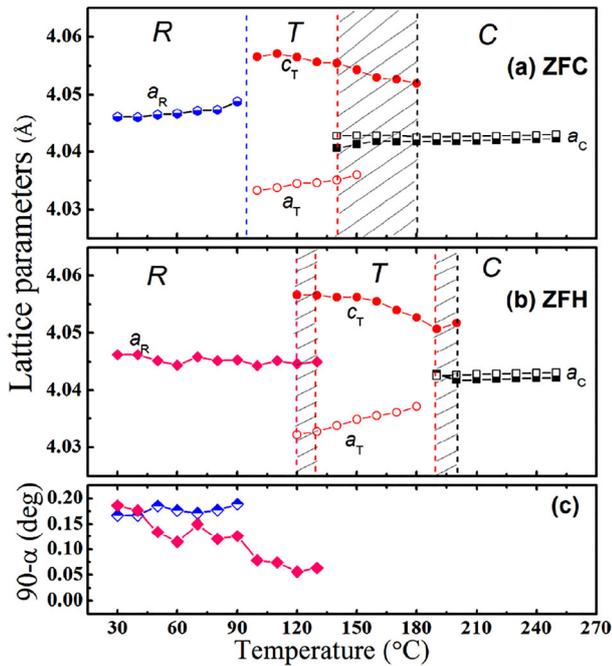


Figure 2 (Color online) Lattice parameters of 25%PIN-42%PMN-33%PT crystals for (a) ZFC and (b) ZFH processes, and (c) the tilt angles for R phase. Note that the open squares are obtained from $(220)_c$ diffraction data and the solid ones are obtained from the $(002)_c$ peaks at high temperature [4].

Note that the shadow regions indicate the coexistence of adjacent two phases and the phase-transition temperatures derived by cooling and heating have a deviation since the crystal structure exhibits thermal hysteresis. Therefore, the temperature-dependent XRD can determine ferroelectric phase transitions rapidly and nondestructively. Unfortunately, the disadvantages of XRD are that it cannot supply more information about other chemical and physical properties (lattice dynamics, optical constants, absorption, band gap, etc).

2.2 Dielectric permittivity in a low frequency region

In the frequency region of $10\text{--}10^6$ Hz, temperature dependent dielectric permittivity of dielectric materials can be determined by using a LCR meter equipped with a temperature chamber [48–50]. For example, Figure 3(a) shows the temperature-dependent dielectric permittivity of PMN-32%PT relaxor ferroelectric at some typical frequencies [25]. Obviously, there are two peaks upon heating. The first one near 379 K indicates the ferroelectric R to ferroelectric T phase transition. The other one (T_m) near 410 K corresponds to the phase transition from ferroelectric T phase to paraelectric C phase. It should be emphasized that the second peak becomes broadening and weak with increasing frequency. It indicates the relaxor behavior of diffuse phase transitions, which is consistent with other PT-based relaxor ferroelectrics [50,51]. For a further step to understand the

relationship between phase transitions and dielectric permittivity, the dielectric behavior at the temperature above T_m was characterized by the Curie-Weiss law: $\varepsilon'(T)=A/(T-T_{CW})$ [25]. Here the parameter A is the Curie-Weiss constant and T_{CW} is the Curie-Weiss temperature. The corresponding fitting results of inverse dielectric permittivity $1/\varepsilon'$ as a function of temperature at 10 kHz are show in Figure 3(b). There are three characteristic temperatures of about 410 K (T_m), 453 K (T_{CW}), and 514 K (T_B). Note that T_B denotes the Burns temperature from which dielectric behavior follows the Curie-Weiss law. Moreover, the dielectric behavior in the temperature region between T_m and T_B follows the empirical Lorentz type relation: $\varepsilon'(T)=2\delta^2\varepsilon_A/[(T-T_A)^2+2\delta^2]$, where ε_A and T_A are the fitting parameters, and δ denotes the diffuseness of permittivity peak. Therefore, the temperature-dependent dielectric permittivity can characterize ferroelectric phase transitions directly. However, a disadvantage is that phase transition temperatures are less accurate because the external influence from the interface and electrodes cannot be avoided.

2.3 Temperature-dependent domain structure

In poled ferroelectric materials, domain structures are related to various crystal structures [52–54]. As shown in Figure 1, the polarization direction is deviation in different symmetries and it will rotate by applying electric field [3]. The

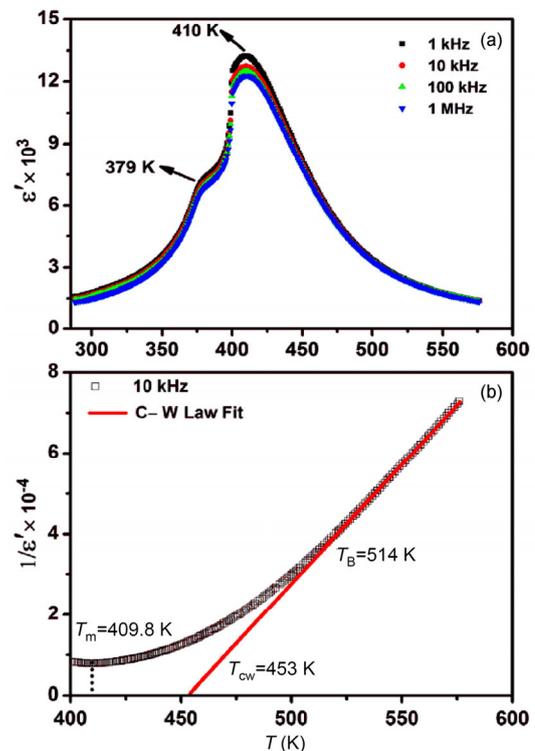


Figure 3 (Color online) (a) Temperature-dependent dielectric permittivity of PMN-32%PT single crystals at different frequencies; (b) the experimental (dotted line) and Curie-Weiss law fitting (solid line) $1/\varepsilon'$ as a function of temperature at 10 kHz [25].

observation of domain configurations using polarizing light microscopy is based on the birefringence of the crystal. Taking the $[011]_C$ poled PMN-0.33PT single crystal as an example, its phase transition sequence and domain configuration evolution on heating and cooling have been investigated in detail [33].

Figure 4 shows the polarizing light microscopy of PMN-0.33PT single crystal and corresponding crystal symmetries are inferred based on the extinction position and orientation of domains. Accurately, during heating process, the structure is a mixture of M_A and O phases at room temperature as shown in Figure 4(a). On heating, the sample becomes less transparent (Figure 4(b)) and then complete extinction at 45° (Figure 4(c)), while transparent at 0° (Figure 4(d)). The single domain configuration of O or R phase can explain the phenomenon. Therefore, the crystal structure belongs to R phase until 93°C , at which R domains disintegrated dramatically and a new phase (M_C) was observed as shown in Figure 4(e) and (f). When the temperature further increases till 155°C , another dramatic change (extinction) of domain structure appears (Figure 4(g)) and its inset indicates the formation of C phase with a small fraction of R phase nanodomain clusters. Finally, the remaining R phase cluster changes into the C phase upon further heating as shown in Figure 4(i) and (j). Therefore, the $[011]_C$ poled PMN-0.33PT crystal has a serious phase transitions ($M_A+O \rightarrow R \rightarrow M_C \rightarrow C$ phases) upon heating. On the other hand, the right-hand two columns III and IV of Figure 4 show the domain structure at various temperatures on cooling. It suggests that the crystal belongs to C phase in the temperature region above 141°C (Figure 4(i) and (ii)). On

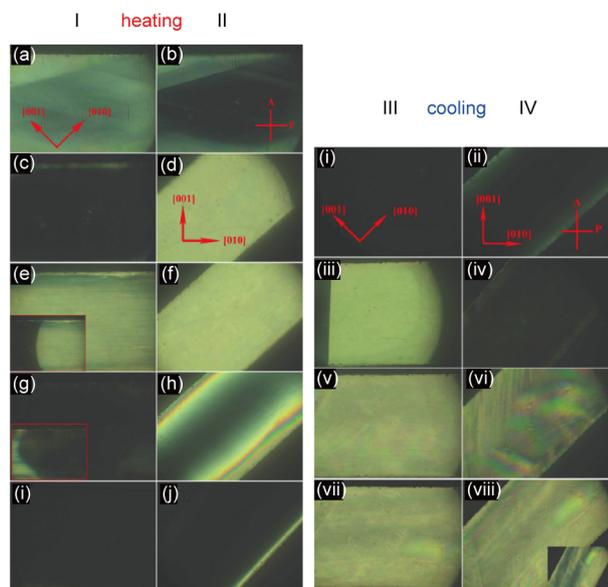


Figure 4 Columns I and II: domain structures of PMN-0.33PT crystal observed at various temperatures on heating at (a) 30°C ; (b) 40°C ; (c,d) 55°C ; (e,f) 93°C ; (g,h) 155°C ; and (i,j) 170°C . Column I corresponds to $\theta=45^\circ$ and II corresponds to $\theta=0^\circ$. Column III and IV: domain structures observed on cooling at (i,ii) 150°C ; (iii,iv) 141°C ; (v,vi) 68°C ; and (vii, viii) 30°C . Column III corresponds to $\theta=45^\circ$ and IV corresponds to $\theta=0^\circ$ [32].

further cooling till 48°C , dramatic domain changes as shown in Figure 4(iii) and 6(iv) and a new phase (T) appears because of extinction at 0° and transparency at 45° . And then another phase (M_A) occurs based on the abrupt changes of domain structure and there is no more phase on further cooling (Figure 4(v)–(viii)). Therefore, the crystal undergoes the structure transitions from $C \rightarrow T \rightarrow M_A$ phases on cooling. In summary, upon heating, it goes through the phase transitions from the M_A and O mixture phase to R phase at 55°C , to M_C phase at 93°C , and finally to C phase at 155°C . On the other hand, the crystal is transformed from C to T phase at 141°C and M_A phase at 68°C on cooling [33]. Therefore, the high sensitivity of the polarized light transmission intensity to the orientation of the optical indicatrix makes optical microscopy a powerful tool to study the crystal symmetry and phase transition sequence according to the various domain structures. However, the limitation of the techniques is that it most commonly used on birefringent samples and the plate samples should be thinned in order to reduce the overlap of domains along the observing direction [32].

3 Novel spectroscopic techniques

To avoid the disadvantages of traditional techniques for investigating ferroelectrics, some novel condensed matter spectroscopic techniques (Raman scattering, SE, transmittance, as well as PL spectra) are used for probing ferroelectric phase transitions and diagrams based on optical band gap, electronic transitions, optical constants, Raman- and infrared-active phonons, and other physical parameters [55–69].

3.1 Raman spectroscopy

Raman and infrared spectra are usually used in condensed matter and material physics and chemistry since vibrational information is specific to the lattice dynamics, symmetries, and chemical bonds. It can provide a fingerprint by which crystal structures and molecules can be identified [70–73]. For examples, the temperature-dependent polarized Raman scatterings of PZN-7%PT, 27%PIN-40% PMN-33%PT, and 95%($K_{0.5}Na_{0.5}$) NbO_3 -5%Li NbO_3 (KNN-5%LN) ferroelectric single crystals have been investigated in detail as following [34,72,73].

Figure 5 shows the polarized Raman spectra of the $\langle 001 \rangle$ -orient PZN-7%PT crystal with various temperatures in the VV (the polarizer and analyzer in vertical position) and VH (the polarizer in vertical position and the analyzer in horizontal position) scattering geometries. It should be emphasized that all measured Raman spectra were divided by the Bose-Einstein occupation number $n+1=1/[1-\exp(-\hbar\omega/k_B T)]$ to get rid of trivial temperature dependence. Here \hbar and k_B are Planck and Boltzmann constants, respec-

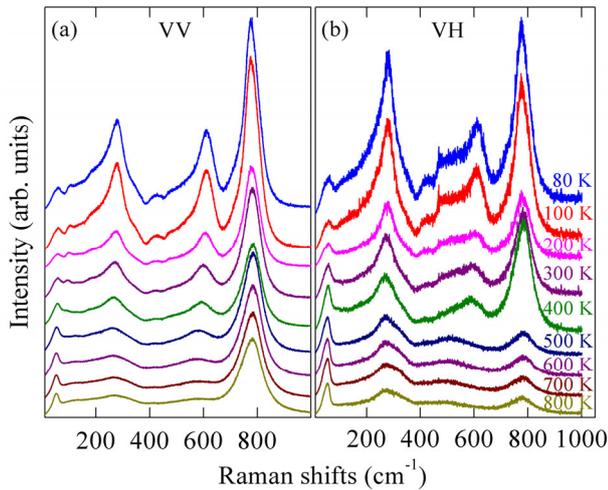


Figure 5 (Color online) (a) VV and (b) VH polarized Raman spectra of the PZN-7%PT single crystal at different temperatures. Note that each spectrum is shifted in intensity for clarity [72].

tively [74]. Upon heating, the polarized Raman spectra have a similar shape except that the intensity of the band near 780 cm^{-1} has a dramatic decrease in the VH geometry compared to that in VV one. Moreover, the band located at about 600 cm^{-1} in the VH scattering geometry vanishes on further heating. These phenomena suggest that the crystal structure of PZN-7%PT changes and there are phase transitions in the temperature region of 300–600 K [72].

The peak positions, integrated intensity, and linewidths (full width at half maxima, FWHM) of Raman modes for PZN-7%PT crystals are obtained by fitting the polarized Raman spectra with multi-Lorentzian functions. Some typical simulation results are shown in Figure 6. Accurately, the two bands near 50 cm^{-1} origin from Pb localized modes. The lower one originates from the Pb1 surrounded by Nb^{5+} ions, which reflects the ferroelectric long-range order. On the other hand, the higher one arises from the Pb2 surrounded by Zn^{2+} and Nb^{5+} ions. The phase transition (R→T→C) temperatures as well as an intermediate temperature are successfully extracted based on the various trends of integrated intensity and FWHM with increasing the temperature (Figure 6(a) and (b)). The results can be confirmed by some other first-order Raman-active modes as shown in Figure 6(c)–(h). Theoretically, the mode near 270 cm^{-1} arises from vibrations of off-centered B-site cations. It is sensitive to the development of polar order, which is related to the coupling processes at the intermediate temperature [75]. Moreover, the one at about 600 cm^{-1} is related to oxygen bending vibration [76]. Obviously, the peak near 780 cm^{-1} is strong and its physical parameters can be obtained very well. This mode can effectively reflect the subtle changes in the lattice structure [77]. Based on the temperature-dependent polarized Raman-active mode behaviors, the PZN-7%PT ferroelectric crystal undergoes two phase transitions from ferroelectric R to ferroelectric T phases and

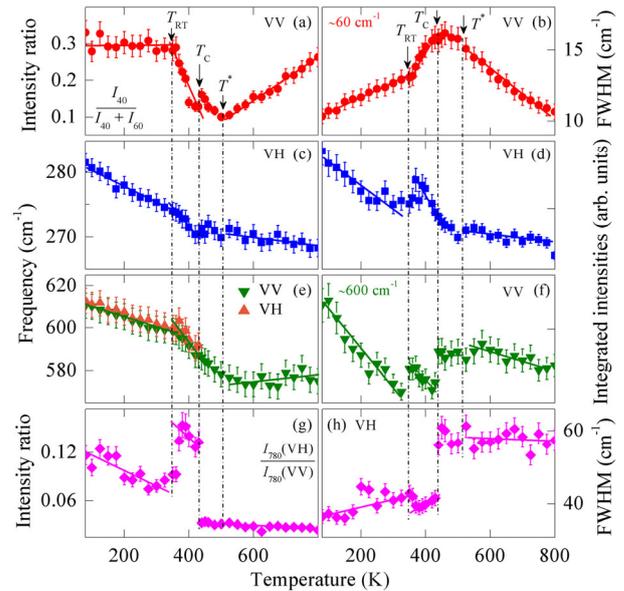


Figure 6 (Color online) Temperature dependence of (a) integrated intensity ratio $I_{40}/(I_{40}+I_{60})$ and (b) FWHM of $\sim 60\text{ cm}^{-1}$ in the VV geometry; (c) peak positions and (d) FWHM of $\sim 270\text{ cm}^{-1}$ in the VH geometry; (e) peak positions in the VV and VH geometries; and (f) FWHM in the VV geometry of the mode near 600 cm^{-1} ; (g) integrated intensity ratio $I_{780}(\text{VH})/I_{780}(\text{VV})$ between VH and VV geometries and (h) FWHM in the VH geometry of the mode near 780 cm^{-1} [72].

from ferroelectric T to paraelectric C phases at 360 and 440 K, respectively, as well as an intermediate temperature ($T^*\sim 510\text{ K}$) upon heating [72].

Moreover, the phase transitions of 27%PIN-40%PMN-33%PT crystals can also be observed by the intensity of polarized Raman-active modes with increasing temperature as shown in Figure 7. The dotted lines show the respective transition temperatures, including the coexistence of multiple (R, M, and O) phases → R phase transition at 325 K, R → T phase transition at 390 K, and T → C phase transition (T_C) at 460 K. In addition, the phase transitions (O→O+T→T→C) of KNN-5%LN can also be observed by the frequency trends of Raman modes on heating in the temperature region of 300–800 K [34]. Therefore, the temperature-dependent Raman spectroscopy is a useful technique to detect phase transitions of functional ferroelectrics directly and nondestructively according to the various trends of peak positions, intensity, and bandwidth as a function of temperature. However, a limitation is that it is difficult to identify the assignments of first-order Raman modes due to the peak overlaps and second-order modes, which will decrease the accuracy of analysis.

3.2 Ellipsometric spectroscopy

Based on the reflectance configuration, SE is an effective tool to extract simultaneously thickness and optical constants of a multilayer system [78–83]. It is a nondestructive

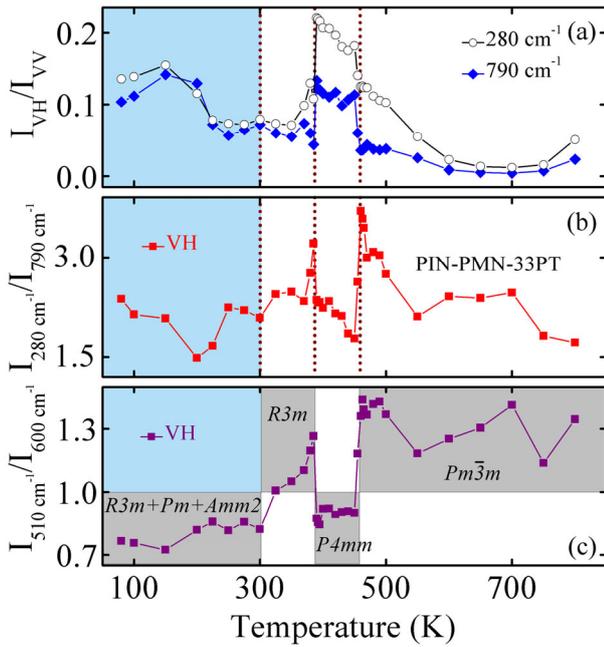


Figure 7 (Color online) Temperature dependence of (a) the intensity ratio of the modes near 280 and 790 cm⁻¹, and the intensity ratio between the modes (b) 280 and 790 cm⁻¹; (c) 510 and 600 cm⁻¹ in the VH geometry for 27%PIN-40%PMN-33%PT crystal [73].

and sensitive optical technique, which measures the relative changes in the amplitude and phase of particular directions for polarized lights upon oblique reflection from the sample surface [72]. The physical parameters measured by ellipsometry are the complex ratio $\rho(E)$ in terms of $\Psi(E)$ and $\Delta(E)$, which are defined by the formula $\rho \equiv r_p/r_s = \tan\Psi e^{i\Delta}$, here, r_p and r_s are the complex Fresnel's reflection coefficient of the light polarized parallel and perpendicular to the incidence plane, respectively. The ellipsometric parameters Ψ and Δ are related to photon energy E , incident angle θ , thickness d , and dielectric functions $\varepsilon(E)$ of measured materials [72,83]. For bulk materials with idealized smooth surface, the dielectric functions can be calculated directly [84]:

$$\langle \varepsilon \rangle = \langle \varepsilon' \rangle + i \langle \varepsilon'' \rangle = \sin^2 \theta [1 + \tan^2 \theta (1 - \rho)^2 / (1 + \rho)^2]. \quad (1)$$

Correspondingly, the complex refractive index $N(E)$ can be derived according to the relationship between $N(E)$ and $\varepsilon(E)$ ($N = n - ik = \varepsilon^{1/2}$). Actually, an appropriate model has to be assumed for a bulk material with a rough surface [72]. For the case of a multilayer structure (air/surface roughness layer/bulk material), dielectric functions of each layer should be obtained by fitting experimental SE spectra with an appropriate dielectric mode based on the Fresnel equation, Snell's law, and the light absorption at layer surface [79–84]. Usually, the optical constants of air is unit (refractive index $n=1$) without absorption (extinction coefficient $k=0$). For the case of relaxor-based crystals, dielectric functions of the surface roughness layer can be described by the Bruggeman effective medium approximation ε_{eff} with the assumption

50% void component ε_v and 50% PT-based bulk crystal $\varepsilon_{\text{Bulk}}$ [$0 = 0.5(\varepsilon_v - \varepsilon_{\text{eff}})/(\varepsilon_v - 2\varepsilon_{\text{eff}}) + 0.5(\varepsilon_{\text{Bulk}} - \varepsilon_{\text{eff}})/(\varepsilon_{\text{Bulk}} - 2\varepsilon_{\text{eff}})$] [85]. Additionally, the dielectric response of crystals can be evaluated by the standard critical point model as following [86]: $\varepsilon_{\text{Bulk}} = A_1 - A_2 e^{i\phi} (E - E_k + i\Gamma)^{1/2}$, where the parameter A_1 is a constant. Therefore, a critical point is described by the parameters amplitude A_2 , excitonic phase angle ϕ , electronic transition E_k , and broadening Γ . Correspondingly, the second partial derivation for showing electronic transitions in dielectric functions can be written as

$$\partial^2 \varepsilon_{\text{Bulk}} / \partial E^2 = A_3 e^{i\phi} (E - E_k + i\Gamma)^{-3/2}, \quad (2)$$

here the parameter A_3 is a constant. In order to investigate the intrinsic relationship between optical response and phase transitions of relaxor ferroelectrics, PIMN- x PT, PZN- x PT and other crystals around MPB have been studied by temperature-dependent ellipsometric spectra [64,72,78].

Figure 8(a) and (b) show the temperature-dependent ellipsometric spectra Ψ and Δ of PIMN-0.33PT crystals, respectively. It suggests that there are two gaps in the original experimental spectra at the temperatures of about 380 and 450 K, which indicates structure changes. Figure 8(c) illustrates the experimental measured at 200 and 400 K and corresponding fitting ellipsometric spectra with a three phase structure (air/surface roughness/crystal). The corresponding dielectric functions are shown in figure 8(d). It suggests that the optical band gap (E_g) is about 3.5 eV. At the energy region below E_g , it is transparent due to the lower value ε'' . Electronic transitions appear above E_g according to the increasing of ε'' . The relationship between ε' and ε'' follows Kramer-Kronig transformation. Moreover, the thickness of surface roughness is about 8 ± 3 nm [78].

To understand the physical mechanism of electronic transitions for PT-based relaxor ferroelectrics, first-principles calculations of bulk PT are performed with the plane-wave pseudopotential calculations based on DFT to elucidate the origins of the critical point features, at the level of the local density approximation (LDA). The cutoff kinetic energy is 380 eV for the cubic perovskite structure of PT and the corresponding lattice constant is 0.397 nm. The calculated band structure and corresponding density of states are shown in Figure 9(a) and (b), respectively. As a matter of fact, the top of valance bands and bottom of conduction bands at the X point consist mainly O-2p and Ti-3d states, respectively. The direct band gap is about 1.64 eV, which is smaller than the experimental gap due to the well-know LDA band-gap error. Moreover, the higher conduction bands originate from mainly Pb-6p and Ti-3d states. On the other hand, the valance bands near -7 eV consist of mainly Pb-6s states. These phenomena are consistent with other results [87].

According to physical mechanism of the Bruggeman effective medium approximation and the standard critical point dielectric function model, electronic transitions de-

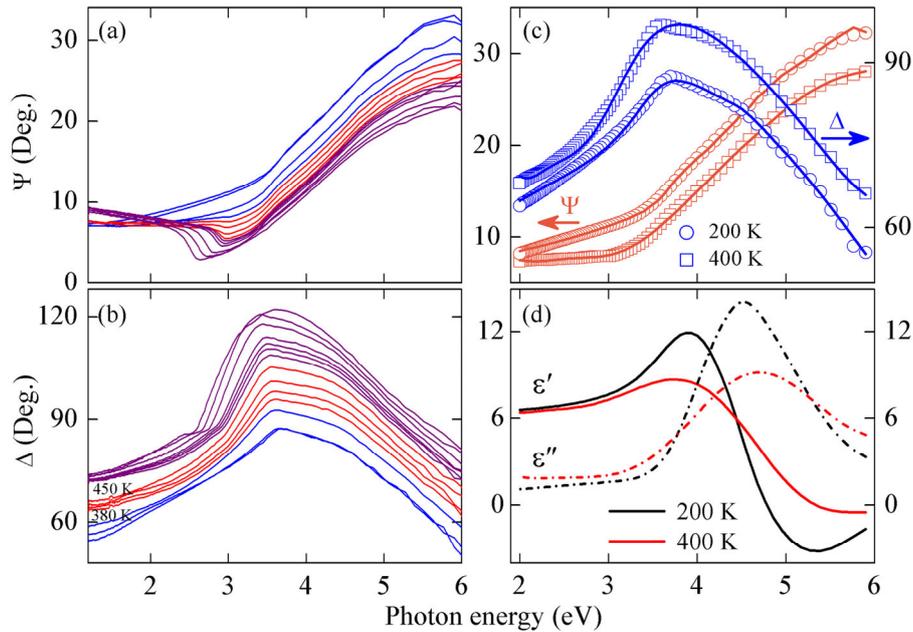


Figure 8 (Color online) Temperature dependence of experimental (a) Ψ and (b) Δ spectra for a PIMN-0.33PT single crystal; (c) the experimental (dotted lines) and fitting (solid lines) Ψ and Δ spectra at 200 and 400 K; (d) the real part (ϵ') and imaginary part (ϵ'') of numerically inverted complex dielectric functions at 200 and 400 K [78].

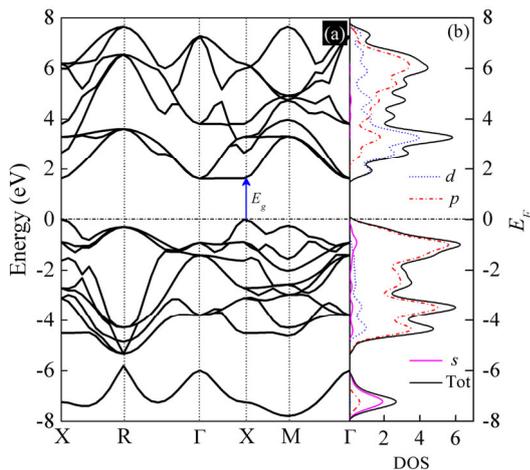


Figure 9 (Color online) (a) Calculated band structure and (b) corresponding partial and total density of states for cubic PbTiO_3 .

rived from eq. (2) are independent of the roughness surface, which affects related dielectric constant. Therefore, the simulation results of electronic transitions and other basic physical parameters for PIMN- x PT crystals have been also extracted by fitting the second partial derivation dielectric spectra $\partial\langle\epsilon'\rangle^2/\partial E^2$ and $\partial\langle\epsilon''\rangle^2/\partial E^2$, and the extracted temperature-dependent electronic transition energy (E_a , E_b , E_c , and E_d) with different PT compositions were plotted in Figure 10 [78]. Theoretically, E_a comes from the electronic transition from O-2p to Ti-d states since there is no E_a transition in the low temperature region (R phase) and the electronic transitions from O-2p (Pb-s) states to Nb-d ones have

larger contribution to E_b . Moreover, the higher electronic transition E_c comes from the O-2p/Pb-s to Pb-p states. The other one E_d is probably derived from the weak Ti/Nb-O hybridization induced by coexistence of multiphase in the MPB region [78,88]. Figure 10 suggests various trends of the four electronic transitions as a function of temperature in PIMN- x PT crystals with different PT compositions. According to the temperature response, there are some phase transitions with increasing the temperature. For the case of PIMN-0.33PT crystal upon heating as shown in Figure 10(c), the temperature of 380 K, at which E_d disappears while E_a appears, is taken as an assignment to determine the phase transition from M_C to T phases. Another transition from T to C phases is found at about 455 K according to the slope changes of E_a , E_b , and E_c .

Based on the temperature response of electronic transitions E_a , E_b , E_c , and E_d , a schematic phase diagram (solid lines) of PIMN- x PT single crystals is shown in Figure 11 [78,89]. It indicates that the R phase locates at the low PT composition side, while the T phase locates at the other side. And the MPB region locates in the PT composition region from 32% to 34%, which separates the R and T phase regions. The results derived from the temperature-dependent SE technique are consistent well with some other previous results (dashed lines) derived by temperature-dependent XRD and dielectric constant at low frequency region from 10^2 to 10^5 Hz [89,90].

In addition, the phase transition process of PZN-7%PT single crystal is also observed by the ellipsometric spectra based on the temperature dependence of the electronic transitions hv_1 , hv_2 and hv_3 , which are derived by fitting the se-

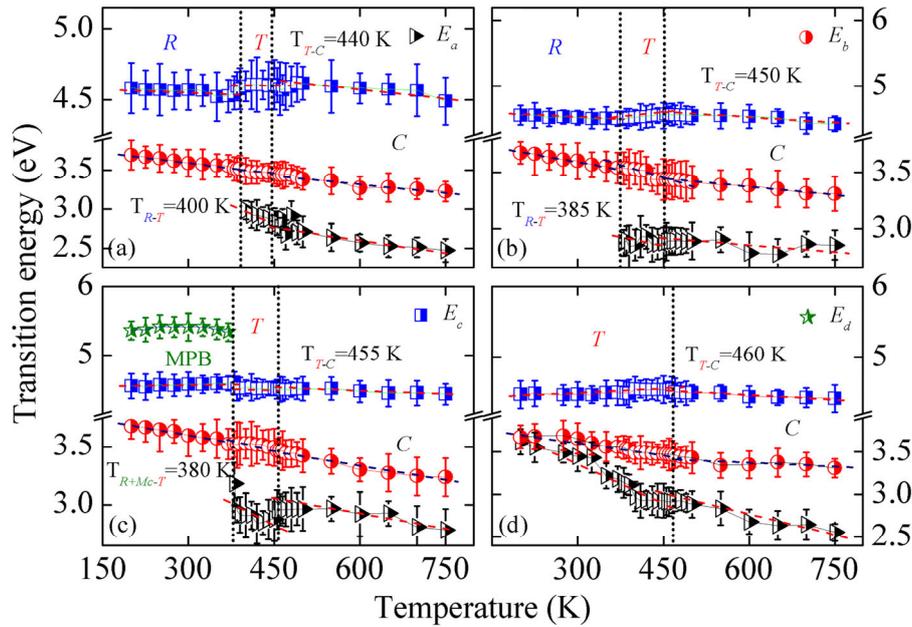


Figure 10 (Color online) Temperature dependence of the interband critical point energies (E_a , E_b , E_c , and E_d) for (a) PIMN-0.29PT, (b) PIMN-0.31PT, (c) PIMN-0.33PT, and (d) PIMN-0.35PT crystals, respectively. The dot lines are applied to guide the eyes and indicate anomaly behavior [78].

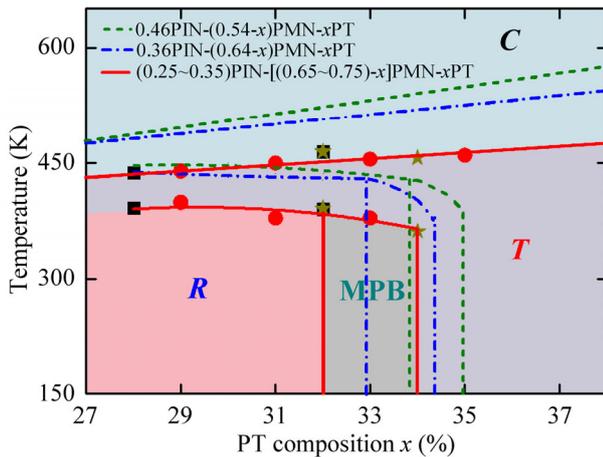


Figure 11 (Color online) A schematic phase diagram of PINM-xPT crystals. The solid lines indicate the phase transition boundary derived from the SE technique [78] and the dashed lines were taken from previous study [89].

cond partial derivatives of experimental pseudodielectric functions $\partial\langle\epsilon\rangle^2/\partial E^2$ with the three phase structure and standard critical point models as shown in Figure 12 [72]. Accurately, the crystal has a phase transition sequence from R to T to C phases at 360 and 440 K upon heating, and the results are consistent with that observed by XRD and other traditional techniques. Therefore, the variable temperature ellipsometry is another effective technique for probing ferroelectric phase transitions and it can supply much more optical properties of film/bulk materials simultaneously. However, it not suitable for investigating powder materials.

3.3 Transmittance spectroscopy

As we know, the absorption coefficient α of functional materials can be characterized by transmittance spectra T based on the Beer's law: $T=I/I_0=e^{-\alpha d}$, here I and I_0 are the intensity of normal incident and transmitted light, respectively. And the parameter d is sample thickness. The material may absorb one color without others since α is a function of incident light frequency. Figure 13 shows the temperature dependence of transmittance spectra of PMN-0.12PT bulk crystals [91]. It suggests that the absorption edge located at about 400 nm presents a typical red-shift trend on heating due to the Bose-Einstein law. Moreover, the corresponding optical band gap E_g can be derived by the Tauc law: $(\alpha E)^n=A(E-E_g)$, here $n=2$ and $1/2$ for direct and indirect materials, respectively. For the direct PMN-0.12PT ferroelectric materials, the band gap can be identified according the intercept of $(\alpha E)^2$ vs. E as shown in the inset of Figure 13.

In addition, Figure 14 shows the phase diagram of PMN-xPT based on the optical band gap derived by temperature and PT composition dependent transmittance spectra. It indicates a relationship between the band gap and phase transitions. Moreover, the experimental transmittance and corresponding absorbance can also directly probe structure variations of NaBiTiO₃-6%BaTiO₃ (NBT-6%BT) crystals directly [35]. Therefore, temperature-dependent transmittance spectroscopy is another effective tool to detect ferroelectric phase transitions nondestructively [91–93]. However, it is unsuitable for investigating opaque materials without optical band gap.

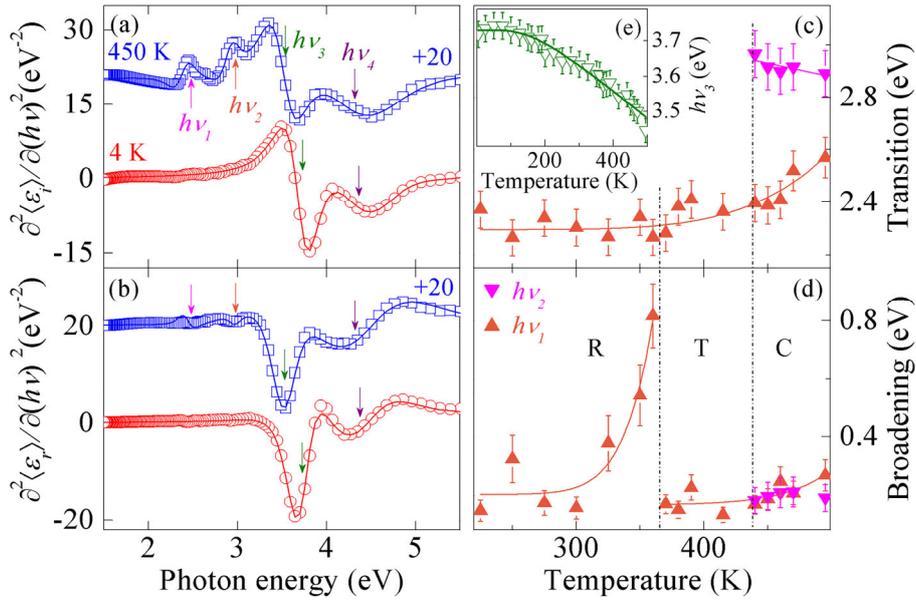


Figure 12 Experimental (dotted lines) and best-fitted (solid lines) second partial derivatives of the (a) imaginary $\langle \epsilon_i \rangle$ and (b) real $\langle \epsilon_r \rangle$ parts of pseudodielectric functions for PZN-7%PT single crystal at 4 and 450 K, respectively; (c) transition energies and (d) broadenings of $h\nu_1$ and $h\nu_2$ as a function of temperature; (e) temperature dependence of the transition energy (dotted lines) $h\nu_3$. The solid lines in (d) and (e) are the fitting results by the Bose-Einstein model [72].

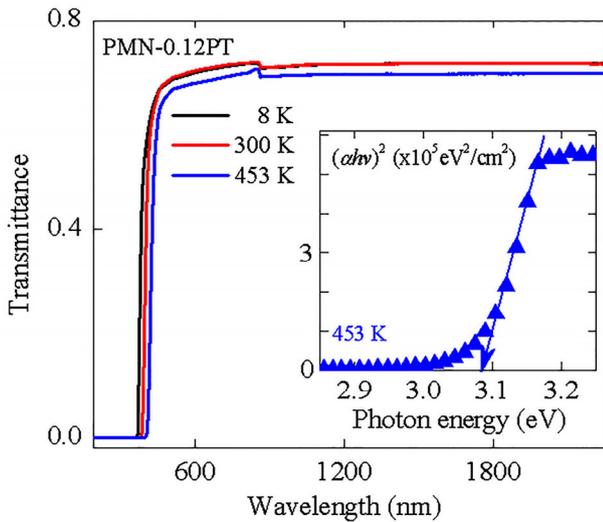


Figure 13 Temperature dependence of transmittance for PMN-0.12PT crystals and the inset is the function of $(ah\nu)^2$ as photon energy to determine the optical band gap [91].

3.4 Photoluminescence spectroscopy

PL spectroscopy, which is another nondestructive, noncontact, and high sensitivity tool, is widely used to investigate photo-physical and photo-chemical properties of functional materials in optoelectronics and photo-catalysis fields. Moreover, the PL technique can supply much information such as lattice defects, surface/subsurface oxygen vacancies, as well as the separation and recombination of photo-induced charge carriers in amorphous, polycrystalline, and-crystal bulks and films [69,80]. Additional, the activation

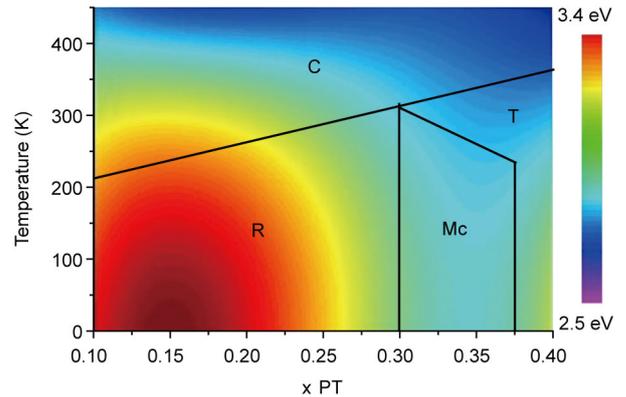


Figure 14 The phase diagram of PMN-xPT based on the optical band gap with various temperatures and PT compositions [91].

energy E_u for the thermal quenching process can be obtained according to temperature-dependent intensity I of PL emissions: $I = I_0 / (1 + a e^{E_u/k_B T})$, where the parameter $a = \tau_r / \tau_0$ and τ_r is the radiative lifetime of electronic transitions from excited states to ground ones, and k_B is the Boltzmann's constant. Usually, PL spectroscopy is used as a diagnostic and development technique to develop electroluminescent devices such as light emitting lasers and diodes [94].

Figure 15(a) shows the experimental (dotted lines) and fitted (solid lines) PL spectrum of PMN-0.33PT crystals at 80 K. The emission E_a near 3.0 eV is ascribed to the optical band gap. It indicates a negative band gap narrowing trend due to lattice thermal expansion or renormalization of band structure by electron-phonon interaction (Figure 15(b)). The others (E_b , E_c , E_d , and E_e) are originated from bound states

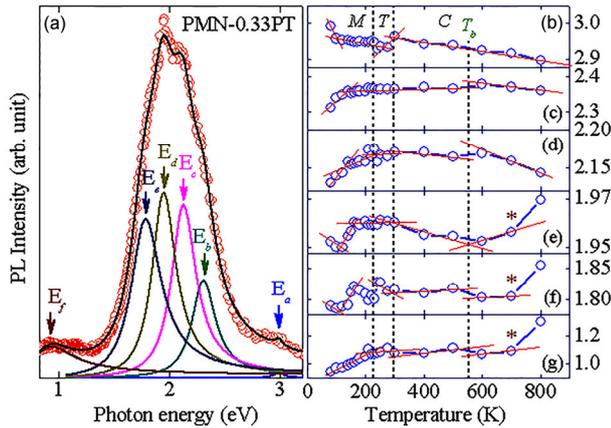


Figure 15 (Color online) (a) Deconvolution of the PL spectrum (solid line) for PMN-0.33PT crystals at 80 K and corresponding well-fitted emissions (b) E_a , (c) E_b , (d) E_c , (e) E_d , (f) E_e , and (g) E_f on heating. Note that the symbol “*” marks the inflection point at 700 K [69].

within the band gap and have various behaviors with increasing the temperature as shown in Figure 15(c)–(g), respectively. The slightly abnormal trends at around 220 K come from the transition between M and T phases. Moreover, another transition temperature from T to C phases as well as the Burns temperature T_B are observed at about 300 and 550 K, respectively [69]. Therefore, PL is another condensed matter spectroscopy for detecting phase transitions of ferroelectric functional materials with lower electronic transition energies than that of the exciting laser.

4 Conclusion and prospect

In the review, we focus on detecting phase transitions of PT-based ferroelectric functional materials by using the condensed matter spectroscopic techniques such as SE, transmittance, PL as well as Raman scattering. Specifically, the temperature-dependent polarized Raman-active mode behaviors indicate that PZN-7%PT undergoes two phase transitions as well as an intermediate temperature upon heating. Moreover, phase diagrams of PIMN- x PT and PMN- x PT were sketched based on the various temperature responses of electronic transitions derived from ellipsometric and transmittance spectra, respectively. Compared to the traditional techniques (XRD, low frequency dielectric permittivity, etc.), optical techniques are nondestructive and noncontact, and can effectively supply much more information about physical and chemical properties (dielectric constant, optical band gap, electronic band structure, lattice dynamics, etc.) besides phase transitions and phase diagrams of ferroelectrics. In addition, it should be improved theoretically and experimentally as a novel technique for probing phase transitions in ferroelectric functional materials to overcome their disadvantages and limitations. At present, it is a better way to investigate phase transitions by combining traditional and novel techniques.

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